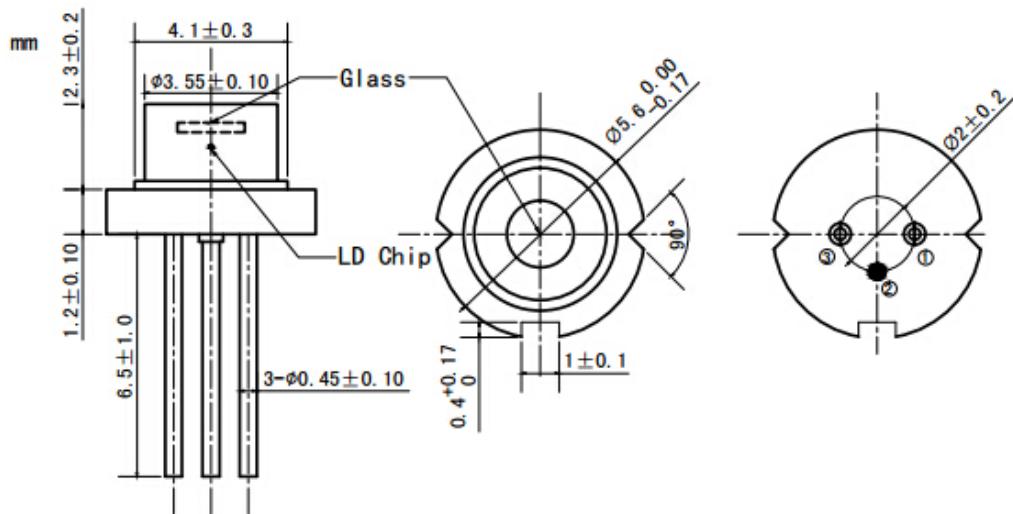


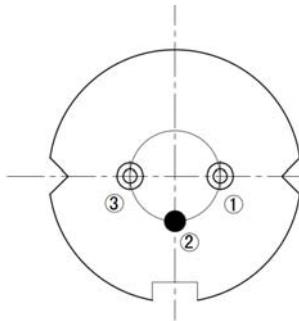
785nm Laser Diode PD		120mW/SM		en.wavespectrum-laser.com.cn		
Reverse Voltage	V_r	2.0		V		
Operating Temperature	T_{op}	-10~+60		°C		
Storage Temperature	T_{stg}	-40~+85		°C		
Lead soldering temperature (10 sec.)	T_{is}	260		°C		
Features:	<ul style="list-style-type: none"> ● 785nm ● Single Mode ● Built-in PD ● TO18 Package 					
Applications:	<ul style="list-style-type: none"> ● Medical Laser Treatment ● Laser Indicator ● Laser Detector 					
Specifications	WSLD-785-120m-1-PD					
		Min	Type	Max		
Center Wavelength@25°C		775nm	785nm	795nm		
Spectral Width (FWHM)	2.0nm					
Output Power			120mW			
Laser Type	FP					
Beam mode	Single Transverse Mode					
Recommend Operating Temperature	25°C					
Beam Divergence (FWHM)			17°_± x 10°_{//}			
Monitor Current			0.3mA			
Slope Efficiency			0.9mW/mA			
Threshold Current (Typ.)			35mA	60mA		
Operating Current (Typ.)			170mA	200mA		
Operating Voltage			2.4V	3.0V		
Package Style	TO18					



TO18(5.6mm) Package View



PIN Bottom View:



1	LD(-)
2	LD(+)&PD(-)
3	PD(+)

Electrically shorten LD module and store in non-extreme conditions.

Suggest using the constant current power supply.

